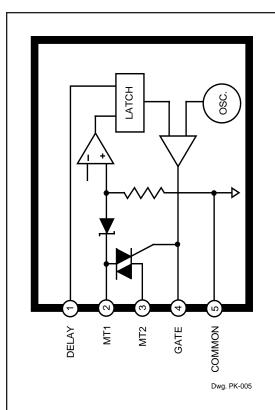
# STR83145 AND STR84145

#### **INTERIM ISSUE**

(subject to change without notice)
August 16, 1994



#### ABSOLUTE MAXIMUM RATINGS

Repetitive Peak OFF-State Voltage, V <sub>DRM</sub> 500 V
Static ON-State Current, I <sub>T(RMS)</sub> 10 A         STR83145       12 A
Non-Repetitive Surge ON-State Current, I <sub>TSM</sub> STR83145
Package Power Dissipation, P <sub>D</sub> See Graph
Triac Junction Temperature, T <sub>J</sub> +125°C
Frame Temperature, T <sub>M</sub> +100°C
Operating Temperature Range, T <sub>A</sub> 20°C to +125°C
Storage Temperature Range, T <sub>stq</sub> 40°C to +125°C

# LATCHED, UNIVERSAL INPUT-VOLTAGE SWITCHES

Intended for power supplies with universal inputs (85 V to 265 V rms), the STR83145 and STR84145 latched, universal input-voltage switches incorporate timing, control, and drive circuitry with a high-current triac (bidirectional triode thyristor) switch. Each device senses the applied ac line potential and automatically switches the rectifier and associated capacitors between a voltage-doubler configuration (for line voltages to 141 V) and a full-bridge configuration (for line voltages greater than 149 V). This eliminates the possibility of user error with adjustable jumpers or switches. Also, the related switch-mode power stage need operate only over a reduced range of dc input voltages when compared with "wide input" power supplies using a bridge rectifier only. The reduction in dc input voltage range permits the use of lower-voltage capacitors and leads to a reduction in power stage stresses and power dissipation. The STR83145 and STR84145 differ only in their maximum ac current rating (10 A and 12 A, respectively).

The internal sensitive-gate triac is switched by a temperature-compensated constant-current gate driver driven by a 15 kHz pulse train to reduce power dissipation. The switch-over voltage is accurately set during manufacture for consistent operation. An user-adjustable delay is provided to ensure start-up in the full-bridge mode. Once established (by an input voltage greater than 149 V rms), an integral latch holds the full-bridge mode to preclude false application of the doubler mode during brownouts, voltage droops, or missing cycles.

The requirements of low transient thermal impedance and steadystate thermal resistance are satisfied in a molded, 5-lead single in-line power package. Similar input-voltage switches, with a switch point of 159 V rms, are also available.

#### **FEATURES**

- Low Duty Cycle Triac Drive for Minimum Dissipation
- For Universal Input Operation Between 85 V rms and 265 V rms to 10 A or 12 A
- Internal Latch Prevents False Mode Switching
- Internal Sensitive-Gate Power Triac
- Adjustable Start-Up Delay
- Accurate 145 V rms Switch-Point Voltage
- Low External Parts Count
- Low Power Dissipation
- Low-Power External Parts

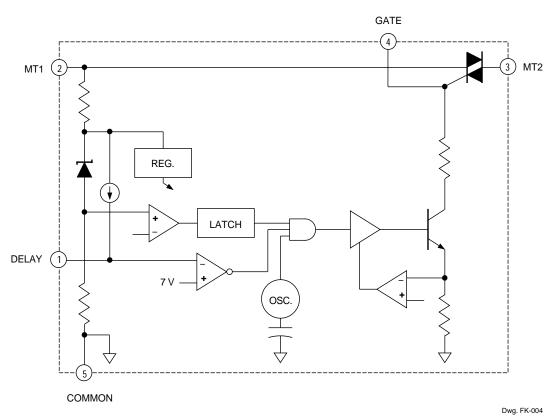
Always order by complete part number:

Part Number	Max. On-State Current
STR83145	10 A rms
STR84145	12 A rms

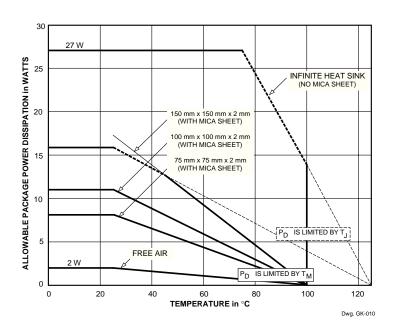




#### **FUNCTIONAL BLOCK DIAGRAM**



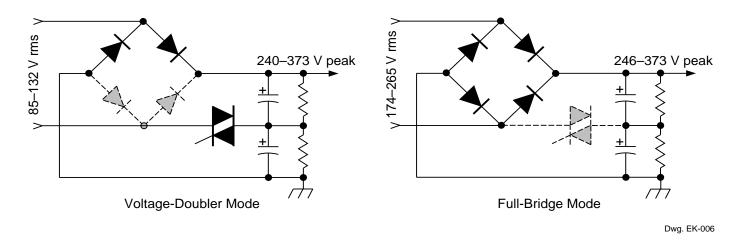
#### ALLOWABLE PACKAGE POWER DISSIPATION







#### SIMPLIFIED OPERATION



# **ELECTRICAL CHARACTERISTICS** at $T_A = +25^{\circ}C$ , voltage measurements are referenced to Common (pin 3) (unless otherwise noted).

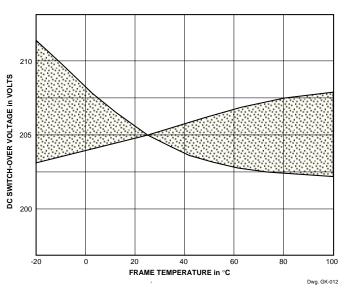
			Limits			
Characteristic	Symbol	Test Conditions	Min.	Тур.	Max.	Units
On-State Voltage	$V_{TM}$	STR83145, I <sub>T</sub> = 10 A*	_	-	1.8	V
		STR84145, I <sub>T</sub> = 12 A*	_	1.6	_	V
Off-State Current	I <sub>DRM</sub>	STR83145, V <sub>D</sub> = 500 V	_	_	100	μΑ
		STR84145, V <sub>D</sub> = 500 V	_	40	_	μΑ
Starting Voltage	V <sub>s</sub>	$V_T = 2 V$	_	-	100	V
Startup Time Delay	t <sub>D</sub>	$C_2 = 1 \mu F, V_{MT1} \ge 100 \text{ V dc}$	40	_	100	ms
DC Switch-Over Voltage	V <sub>C</sub>	V <sub>DELAY</sub> ≤ 1 V	200	205	210	V
Temperature Coefficient						
of Switch-Over Voltage	$\alpha_{_{ m VC}}$	$-20^{\circ}\text{C} \le \text{T}_{\text{M}} \le +100^{\circ}\text{C}$	_	±45	_	mV/°C
Input Current	I <sub>MT1</sub>	Voltage-doubler mode, V <sub>MT1</sub> = 195 V	-	-	10	mA
		Full-bridge mode, V <sub>MT1</sub> = 400 V	_	-	6.5	mA
Delay Terminal Voltage	V <sub>DELAY</sub>		_	_	7.0	V
Triac Gate-Drive Osc. Freq.	f <sub>o</sub>	$V_{gate}$ ref. MT1, $V_{MT1} = 100 \text{ V}$	_	15	_	kHz
Latch Reset Voltage	V <sub>R</sub>	V <sub>GATE</sub> = 400 mV	2.0	_	15	V
Thermal Resistance	$R_{\theta JM}$	FET channel to mounting surface	_	_	1.8	°C/W

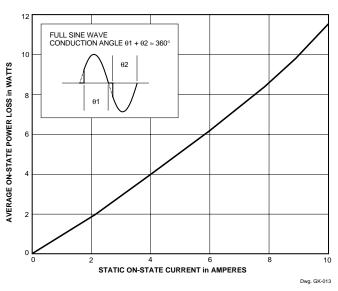
NOTES: Negative current is defined as coming out of (sourcing) the specified device terminal.

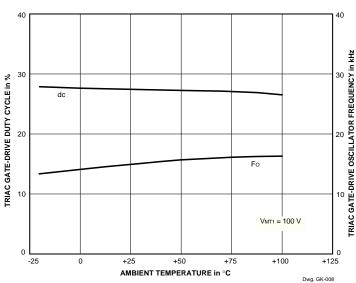
Typical Data is for design information only.

<sup>\*</sup>In practical use, I<sub>T</sub> is recommended derated to 70%.

#### TYPICAL CHARACTERISTICS







#### APPLICATIONS INFORMATION

A WAR

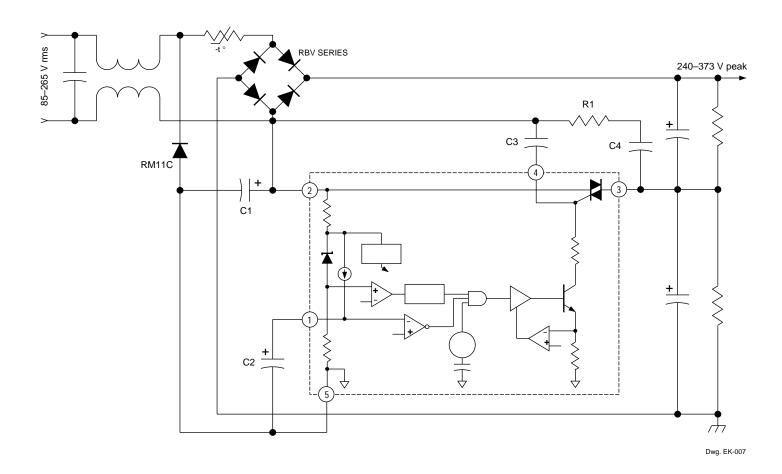
**WARNING** — These devices are designed to be operated at lethal voltages and energy levels. Circuit designs that embody these components must conform with applicable safety requirements. Precautions must be taken to prevent accidental contact with power-line potentials. Do not connect grounded test equipment.

The use of an isolation transformer is recommended during circuit development and breadboarding.





#### **TYPICAL APPLICATION**



External component values have been selected for optimum device performance and reliability. Except for  $C_2$ , component values other than the following may result in false operation of these devices.

$$C_1 = 4.7 \,\mu\text{F}, 400 \,\text{V}$$

$$C_2 = 1 \mu F, 50 V$$

$$C_3 = 0.047 \,\mu\text{F}, 50 \,\text{V}$$

$$C_4 = 0.047 \,\mu\text{F}, \, 250 \,\,\text{V}$$

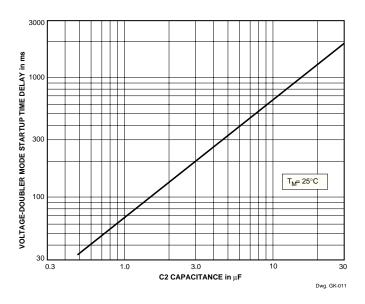
$$R_1 = 4.7 \Omega$$

Turn-ON delay (forced full-bridge mode) may be adjusted for desired system performance:

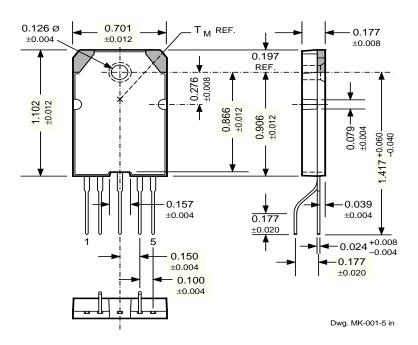
$$t_D \approx 68 \text{ x } C_2$$

where  $t_{\rm D}$  is the delay time in ms

C<sub>2</sub> is capacitance in μF

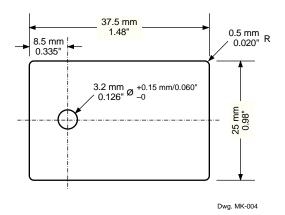


# Dimensions in Inches (for reference only)



#### NOTES:

- 1. Exact body and lead configuration at vendor's option within limits shown.
- 2. Recommended mounting hardware torque: 4.34 5.79 lbf•ft.
- 3. The hatched area is exposed heat spreader, electrically common to pin 3.
- 4. Recommended 0.003" to 0.006" thick mica insulator with metal-oxide-filled, alkyl-degenerated oil base, silicone grease (Dow Corning 340, or equivalent); or Bergquist Sil-Pad<sup>®</sup>.

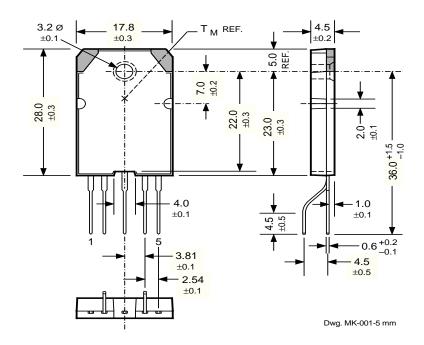






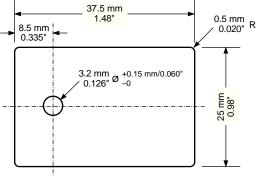
#### **Dimensions in Millimeters**

(controlling dimensions)



#### NOTES:

- 1. Exact body and lead configuration at vendor's option within limits shown.
- 2. Recommended mounting hardware torque: 6 8 kgf•cm (0.588 0.785 Nm).
- 3. The hatched area is exposed heat spreader, electrically common to pin 3.
- 4. Recommended 0.08 mm to 0.15 mm thick mica insulator with metal-oxide-filled, alkyl-degenerated oil base, silicone grease (Dow Corning 340, or equivalent); or Bergquist Sil-Pad®.



Dwg. MK-004

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